MASW-010612



GaAs SP3T Switch DC - 3.5 GHz

Rev. V1

Features

- Low Insertion Loss: 0.6 dB
- High P1dB: 36 dBm
- 0.5 micron GaAs pHEMT Process
- Fast Settling Speed for timing-sensitive applications
- 1.8 V Operation with 1.8 V on Voltage Pull Up
- Lead-Free 1.5 mm 8-Lead PDFN Package
- Halogen-Free "Green" Mold Compound
- RoHS* Compliant and 260°C Reflow Compatible

Description

The MASW-010612 is a GaAs pHEMT MMIC SP3T switch in a lead-free 1.5 mm 8-lead PDFN package. This device is ideal for low control voltage, low insertion loss, high isolation and small size applications.

A typical application is antenna, WLAN and Bluetooth systems that connect separate receive functions to a common antenna. This part is optimized at 2.4 GHz for switching between WLAN and Bluetooth to a single antenna.

The MASW-010612 is fabricated using a 0.5 micron gate length GaAs pHEMT process. The process features full passivation for performance and reliability.

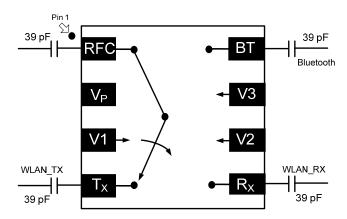
Ordering Information^{1,2}

Part Number	Package
MASW-010612-TR1000	1000 piece reel
MASW-010612-TR3000	3000 piece reel
MASW-010612-001SMB	Sample Test Board

- 1. Reference Application Note M513 for reel size information.
- 2. All sample boards include 5 loose parts.

Commitment to produce in volume is not guaranteed.

Functional Schematic



Pin Configuration

Pin No.	Function Description		
1	RFC	RF In/Out	
2	$V_P^{3,4}$	Optional Voltage Pull Up	
3	V1 ³	Control 1	
4	T _X	RF In/Out	
5	R _X RF In/Out		
6	V2 ³	Control 2	
7	V3 ³	Control 3	
8	ВТ	RF In/Out	
Paddle ⁵	RF, DC and Thermal Ground		

- 3. Depending on system sensitivity optional DC line bypass capacitors (22 pF) may be used.
- Improved linearity at low control voltage can be obtained by tying pin 2 to the most positive control voltage. Otherwise, leave pin 2 unconnected.
- The exposed pad centered on the package bottom must be connected to RF, DC, and thermal ground.

^{*} Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

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Electrical Specifications: Freq: 2.45 GHz, $T_A = 25^{\circ}$ C, $V_C = 0 \text{ V} / 3 \text{ V}$, $Z_0 = 50 \Omega^{6,7}$

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Insertion Loss 8	_	dB	_	0.6	0.85
Isolation	RFC - T _X , R _X , BT	dB	19	21	_
Return Loss	_	dB	_	20	_
IP3	Two Tone, +10 dBm/tone, 10 MHz Spacing	dBm	_	54	_
P1dB	T _X R _X BT	dBm	_	36 34 34	_
3rd Harmonic	+20 dBm	dBc	_	-78	_
Trise, Tfall	10% to 90% RF, 90% to 10% RF	ns	_	16 20	_
Ton, Toff	50% control to 90% RF, 50% control to 10% RF	ns	_	26 30	_
Control Current	V _C = 3 V	μΑ	_	4	10

^{6.} For positive control voltage, external DC blocking capacitors are required on all RF ports.

Absolute Maximum Ratings 9,10

Parameter	Absolute Maximum	
Max Input Power (0.5-3.5 GHz, 3 V Control) RFC – T _x RFC – R _x RFC – BT	35 dBm 31 dBm 31 dBm	
V _{HI} -V _{LO}	8.5 volts	
Operating Temperature	-40°C to +85°C	
Storage Temperature	-65°C to +150°C	

^{9.} Exceeding any one or combination of these limits may cause permanent damage to this device.

Commitment to produce in volume is not guaranteed.

Truth Table 11,12,13

V1	V2	V3	RFC - T _X	RFC - R _X	RFC - BT
1	0	0	On	Off	Off
0	1	0	Off	On	Off
0	0	1	Off	Off	On

^{11.} $0 = 0 \text{ V} \pm 0.2 \text{ V}$, 1 = 1.8 V to +5 V, minimum $V_{HI}-V_{LO} = 1.8 \text{ V}$, maximum V_{HI} - $V_{LO} = 8.5 V$.

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^{7.} Specifications apply with no connection to pin 2 (V_P).

^{8.} Insertion loss can be optimized by varying the DC blocking capacitor value, e.g. 100 pF for 100 - 500 MHz, 39 pF for 2.45 GHz.

^{10.} M/A-COM Technology Solutions does not recommend sustained operation near these survivability limits.

^{12.} For use at low voltage, M/A-COM recommends connecting pin 2 to a voltage equal to the most positive control voltage.

^{13.} Negative control voltage may be used. The '1' in the table would be the most positive (0 V) and the '0' would be the most negative (-3 V for example).

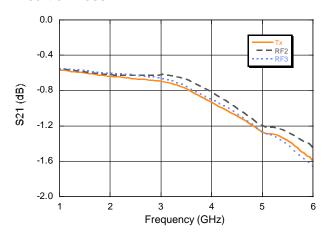


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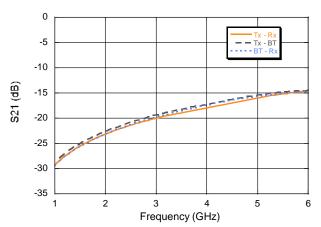
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Typical Performance Curves:

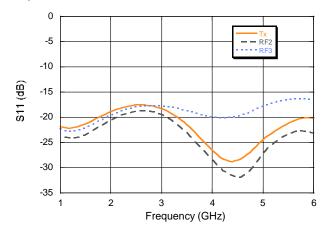
Insertion Loss



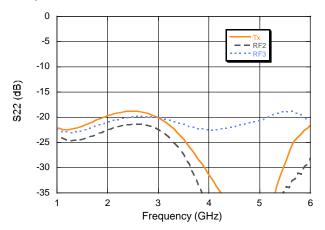
T_X Isolation



Input Return Loss



Output Return Loss



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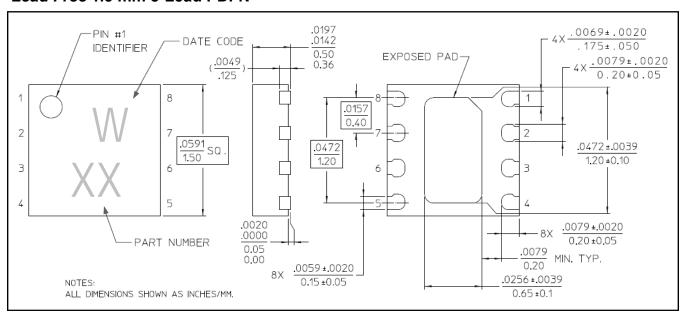
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Lead Free 1.5 mm 8-Lead PDFN[†]



Reference Application Note S2083 for lead-free solder reflow recommendations and PCB footprint information. Meets JEDEC moisture sensitivity level 1 requirements. Plating is NiPdAu over copper.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.